

SI-3000ZFE Series 5-Terminal, Low Dropout Voltage Linear Regulator ICs

■Features

- Compact full-mold package (equivalent to TO220)
- Output current: 3.0A
- Low dropout voltage: $V_{DIF} \leq 0.7V$ (at $I_o = 3.0A$)
- Low circuit current at output OFF: $I_q(\text{OFF}) \leq 1\mu\text{A}$
- Built-in overcurrent and thermal protection circuits

■Applications

- Secondary stabilized power supply (local power supply)

■Absolute Maximum Ratings

(Ta = 25°C)

Parameter	Symbol	Ratings	Unit
DC Input Voltage	V _{IN} ^{*1}	10	V
Output Control Terminal Voltage	V _C	6	V
DC Output Current	I _O ^{*1}	3.0	A
Power Dissipation	P _{D1}	20 (With infinite heatsink)	W
	P _{D2}	1.5 (Without heatsink, stand-alone operation)	W
Junction Temperature	T _j	-30 to +125	°C
Operating Ambient Temperature	T _{op}	-30 to +100	°C
Storage Temperature	T _{stg}	-30 to +125	°C
Thermal Resistance (Junction to Case)	θ _{j-c}	5.0	°C/W
Thermal Resistance (Junction to Ambient Air)	θ _{j-a}	66.7 (Without heatsink, stand-alone operation)	°C/W

■Recommended Operating Conditions

Parameter	Symbol	Ratings	Unit
Input Voltage	V _{IN}	*2 to 6 ^{*1}	V
Output Current	I _O	0 to 3	A
Operating Ambient Temperature	T _{op(a)}	-20 to +85	°C
Operating Junction Temperature	T _{op(j)}	-20 to +100	°C
Output Voltage Variable Range	V _{OADJ}	1.2 to 5	V

*1: V_{IN} (max) and I_O (max) are restricted by the relationship P_D = (V_{IN} - V_O) × I_O.

*2: Set the input voltage to 2.4V or higher when setting the output voltage to 2.0V or lower.

■Electrical Characteristics

(Ta = 25°C, V_C = 2V unless otherwise specified)

Parameter	Symbol	SI-3011ZFE			Unit
		min.	typ.	max.	
Reference Voltage	V _{ADJ}	1.078	1.100	1.122	V
	Conditions	V _{IN} =V _O +1V, I _O =10mA			
Line Regulation	ΔV _{OLINE}			10	mV
	Conditions	V _{IN} =3.3 to 5V, I _O =10mA (V _O =2.5V)			
Load Regulation	ΔV _{OLOAD}			40	mV
	Conditions	V _{IN} =3.3V, I _O =0 to 3A (V _O =2.5V)			
Dropout Voltage	V _{DIF}			0.7	V
	Conditions	I _O =3A (V _O =2.5V)			
Quiescent Circuit Current	I _Q		1	1.5	mA
	Conditions	V _{IN} =V _O +1V, I _O =0A, V _C =2V			
Circuit Current at Output OFF	I _Q (OFF)			1	μA
	Conditions	V _{IN} =V _O +1V, V _C =0V			
Temperature Coefficient of Output Voltage	ΔV _O /ΔT _a		±0.3		mV/°C
	Conditions	T _j =0 to 100°C			
Ripple Rejection	R _{REJ}		60		dB
	Conditions	V _{IN} =V _O +1V, f=100 to 120Hz, I _O =0.1A			
Overcurrent Protection Starting Current ^{*2}	I _{S1}	3.2			A
	Conditions	V _{IN} =V _O +1V			
V _C Terminal	V _C , I _H	2			V
	Control Voltage (Output ON) ^{*3}				
	V _C , I _L			0.8	μA
	Control Current(Output ON)	I _C , I _H		100	
Control Current(Output OFF)	I _C , I _L	-5	0		μA
	Conditions	V _C =2.7V			

*1: Set the input voltage to 2.4V or higher when setting the output voltage to 2.0V or lower.

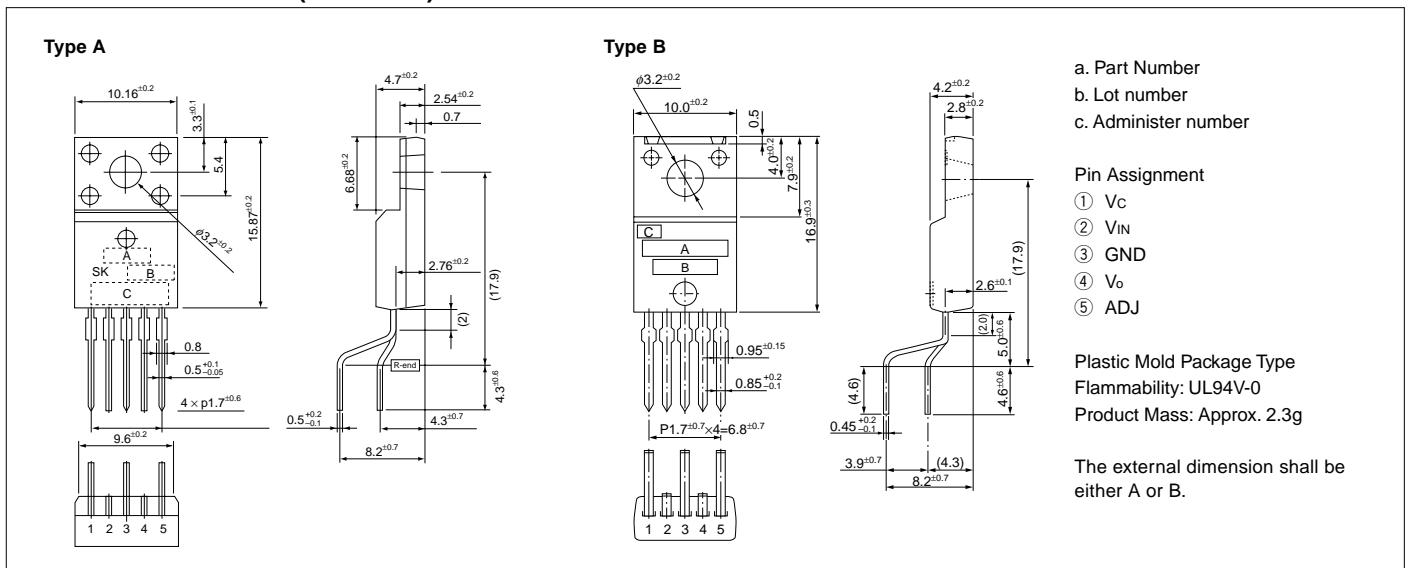
*2: I_{S1} is specified at the 5% drop point of output voltage V_O under the Output Voltage parameter conditions.*3: Output is OFF when the output control terminal V_C is open. Each input level is equivalent to LS-TTL level. Therefore, the device can be driven directly by LS-TTLs.

*4: These products cannot be used in the following applications because the built-in foldback-type overcurrent protection may cause errors during start-up stage.

(1) Constant current load (2) Positive and negative power supply (3) Series-connected power supply (4) V_O adjustment by raising ground voltage

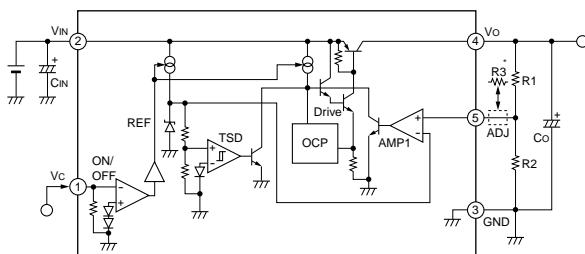
■External Dimensions (TO220F-5)

(unit : mm)



■Typical Connection Diagram/Block Diagram

SI-3011ZFE



CIN: Input capacitor (Approx. 10μF)

This capacitor is required when the input line contains inductance or when the wiring is long.

Co: Output capacitor (47μF or higher)

The output voltage may oscillate if a low ESR type capacitor (such as a ceramic capacitor) is used for the output capacitor in SI-3000ZFE.

R1, R2: Output voltage setting resistors

The output voltage can be set by connecting R1 and R2 as shown at left.
 The recommended value for R2 is 10kΩ or 11kΩ.

$$R1 = (V_o - V_{ADJ}) / (V_{ADJ}/R2)$$

*: Insert R3 in case of setting Vo to $V_o \leq 1.8V$. The recommended value for R3 is 10kΩ.

■Ta-Pd Characteristics

